

2N3704

2N3704 Information



Part Number	2N3704	
Manufacturer	Fairchild/ON Semiconductor	
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single	
Description	TRANS NPN 30V 0.5A TO-92	
Package	TO-226-3, TO-92-3 (TO-226AA)	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



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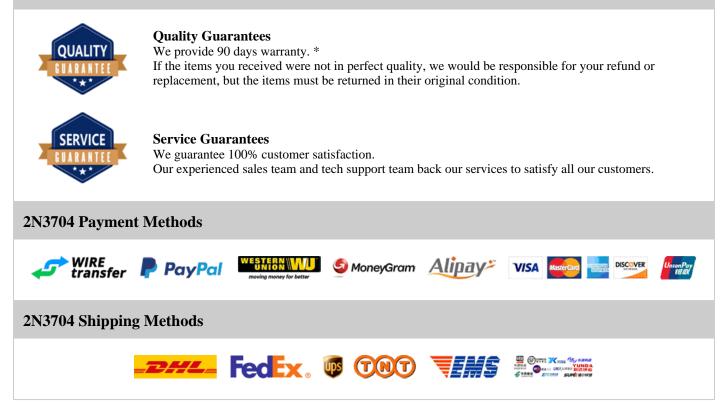
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2N3704 Specifications

Manufacturer Part Number2N3704ManufacturerFairchild/ON SemiconductorCategoryDiscrete Semiconductor Products Transistors - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (L) (Max)SolomAVoltage - Collector Emitter Breakdown (Max)30VVce Saturation (Max) @ Ib, IcIV@ 5mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC current Gain (hFE) (Min) @ Le, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3		
CategoryDiscrete Semiconductor Products Transistors - Bipolar (BJT) - SinglePackageTo-226-3, TO-92-3 (TO-226A)Series-Transistor TypeNPNCurrent - Collector (Lc) (Max)500mAVoltage - Collector Emitter Breakdown (Max)30VVcc Saturation (Max) @ Ib, Ic100mA (ICBO)Current - Collector Cutoff (Max)100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226A, TO-926A,	Manufacturer Part Number	2N3704
Transistor - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226A)Series-Transistor TypeNPNCurrent - Collector (Ic) (Max)500mAVoltage - Collector Emitter Breakdown (Max)30VVce Saturation (Max) @ Ib, IcIV @ 5mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226A, TO-226AA)Supplier Device PackageTO-92-3	Manufacturer	Fairchild/ON Semiconductor
PackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (Lo (Max)500mAVoltage - Collector Emitter Breakdown (Max)30VVce Saturation (Max) @ Ib, Ic1V @ 5mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Category	Discrete Semiconductor Products
Series-Transistor TypeNPNCurrent - Collector (Lo) (Max)500mAVoltage - Collector Emitter Breakdown (Max)30VVce Saturation (Max) @ Ib, IcIV @ 5mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-226AA)Supplier Device PackageTO-92-3		Transistors - Bipolar (BJT) - Single
Transistor TypeNPNCurrent - Collector (Lo (Max)500mAVoltage - Collector Emitter Breakdown (Max)30VVcc Saturation (Max) @ Ib, Ic1V @ 5mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Package	TO-226-3, TO-92-3 (TO-226AA)
Current - Collector (Ic) (Max)500mAVoltage - Collector Emitter Breakdown (Max)30VVce Saturation (Max) @ Ib, Ic1V @ 5mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Series	-
Voltage - Collector Emitter Breakdown (Max)30VVce Saturation (Max) @ lb, Ic1V @ 5mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Transistor Type	NPN
Yce Saturation (Max) @ Ib, IcIV @ 5mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Current - Collector (Ic) (Max)	500mA
Current - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 50mA, 5VPower - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Voltage - Collector Emitter Breakdown (Max)	30V
DC Current Gain (hFE) (Min) @ Ic, Vce 100 @ 50mA, 5V Power - Max 625mW Frequency - Transition 100MHz Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package TO-92-3	Vce Saturation (Max) @ Ib, Ic	1V @ 5mA, 100mA
Power - Max625mWFrequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Current - Collector Cutoff (Max)	100nA (ICBO)
Frequency - Transition100MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 50mA, 5V
Operating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Power - Max	625mW
Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Frequency - Transition	100MHz
Package / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Operating Temperature	-55°C ~ 150°C (TJ)
Supplier Device Package TO-92-3	Mounting Type	Through Hole
	Package / Case	TO-226-3, TO-92-3 (TO-226AA)
Report errors?	Supplier Device Package	TO-92-3
		Report errors?

2N3704 Guarantees



If you have any question about 2N3704, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com